

Barut–Girardello coherent states for anisotropic 2D-Dirac materials

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We construct the Barut–Girardello coherent states for charge carriers in anisotropic 2D-Dirac materials immersed in a constant homogeneous magnetic field which is orthogonal to the sample surface. Working in a Landau-like gauge, the anisotropic Dirac equation is solved for identifying the appropriate arising and lowering operators. The corresponding coherent states are constructed as eigenstates of a generalized annihilation operator with complex eigenvalues which depends on an arbitrary function f of the number operator. In order to describe the anisotropy effects on these states, we obtain the Heisenberg uncertainty relation, the probability density and mean energy value for three different functions f . As an example, the results obtained are discussed for the strained graphene case.

This is joint work with Yajaira Concha-Sánchez and Alfredo Raya.

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